

Abstract:

The invention relates to an aptoelectronic component on a substrate comprising a first and a second electrode
5 wherein the first electrode is arranged on the substrate and the second electrode forms a counterelectrode, wherein at least one photoactive layer system is arranged between said electrodes, wherein the photoactive component furthermore comprises
10 at least one layer or layer sequence configured such that said layer or layer sequence acts as a spectrally selective color filter in the range from 450 nm to 800 nm in the photoactive component.